

3mm Round Standard T-1 Package Phototransistor Technical Data Sheet

Part No.: 304PTD4B-1A



Features:

Standard T-1 (Φ3mm) package.Fast response time.High photo sensitivity.Small junction capacitance.The product itself will remain within RoHS compliant Version.

Descriptions:

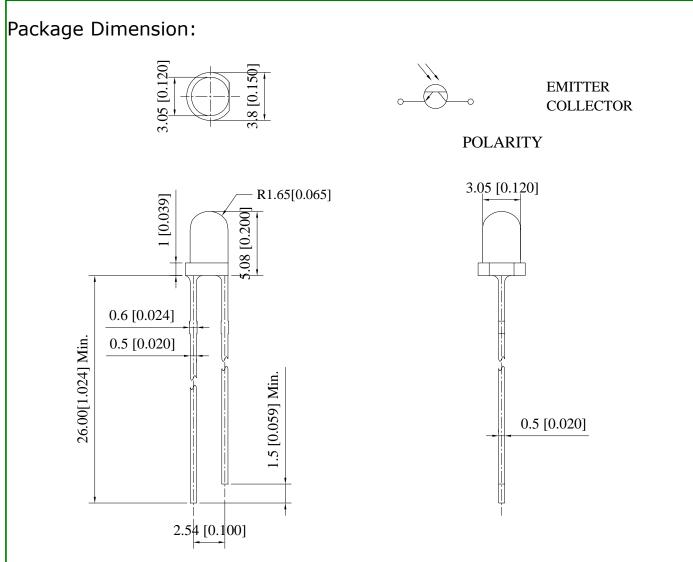
The 304PT is a high speed and high sensitive silicon NPN phototransistor in a standard T-1 (Φ 3mm) epoxy package.

Due to its black epoxy, the device is matched to infrared radiation.

Applications:

Infrared applied system. Counters and sorters. Encoders. Floppy disk drive. Optoelectronic switch. Video camera, tape and card readers. Position sensors.





| Part No. | Chip Material | Lens Color | Source Color |
|-------------|---------------|------------|-----------------|
| 304PTD4B-1A | Silicon | Black | Phototransistor |

Notes:

- 1. All dimensions are in millimeters (inches).
- 2. Tolerance is \pm 0.25 mm (.010") unless otherwise noted.
- 3. Protruded resin under flange is 1.00 mm (.039") max.
- 4. Specifications are subject to change without notice.



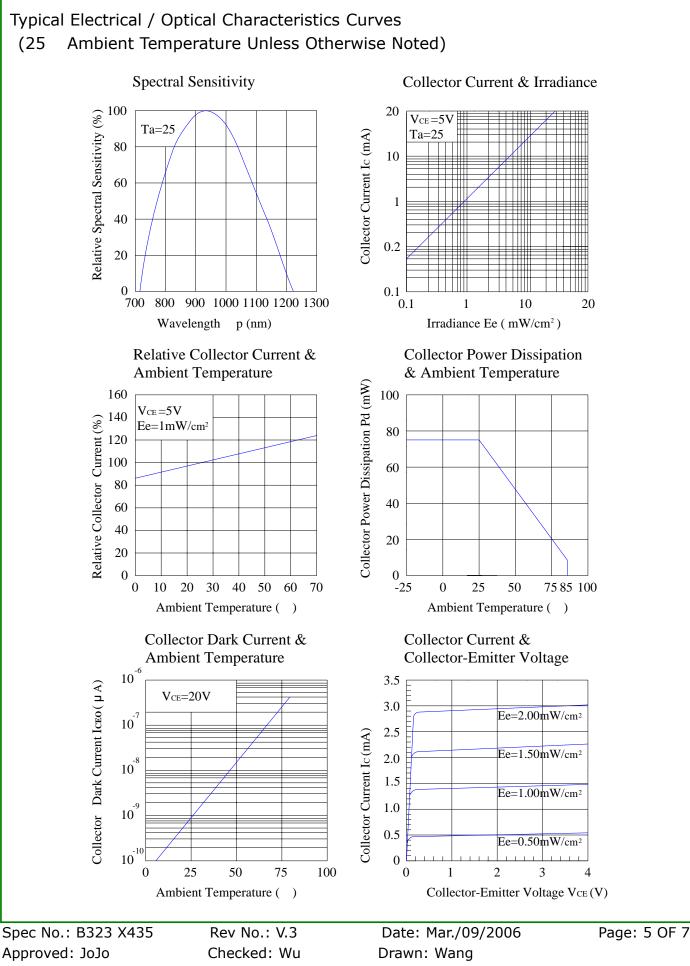
Absolute Maximum Ratings (Ta=25)

| Parameters | Symbol | Rating | Unit |
|--|------------------|------------|------|
| Power Dissipation at (or below) 25 free Air Temperature | P _D | 75 | mW |
| Collector-Emitter Voltage | V _{CEO} | 30 | V |
| Emitter-Collector-Voltage | V _{ECO} | 5 | V |
| Collector Current | I _C | 20 | mA |
| Operating Temperature | Topr | -40 to +80 | |
| Storage Temperature | Tstg | -40 to +85 | |
| Lead Soldering Temperature [4mm (.157") From Body] | Tsol | 260 | |

Electrical Optical Characteristics at Ta=25

| Parameters | Symbol | Min. | Тур. | Max. | Unit | Condition |
|--------------------------------------|----------------------|------|------|------|------|---|
| Collector-Emitter Breakdown Voltage | BV _{CEO} | 30 | | | V | I _C =100µA, Ee=0mW/cm² |
| Emitter-Collector Breakdown Voltage | BV _{ECO} | 5 | | | V | Ie=100µA, Ee=0mW/cm² |
| Collector-Emitter Saturation Voltage | V _{CE(SAT)} | | | 0.40 | V | I _C =0.70mA, Ee=1mW/cm ² |
| Optical Rise Time (10% to 90%) | T _R | | 15 | | ns | V_{CE} =5V, I_{C} =1mA, R_{L} =1000 Ω |
| Optical Fall Time (90% to 10%) | T _F | | 15 | | 115 | |
| Collector Dark Current | \mathbf{I}_{CEO} | | | 100 | nA | $\begin{array}{c} \text{Ee=0mW/cm}^2,\\ \text{V}_{\text{CE}}\text{=}20\text{V} \end{array}$ |
| On State Collector Current | I _{C(ON)} | 0.70 | 2.50 | | mA | $\begin{array}{c} \text{Ee=1mW/cm}^2,\\ \text{V}_{\text{CE}}\text{=}5\text{V} \end{array}$ |
| Reception Angle | 20 _{1/2} | | 30 | | Deg | |
| Wavelength Of Peak Sensitivity | λP | | 940 | | nm | |
| Rang Of Spectral Bandwidth | λ0.5 | 700 | | 1200 | nm | |





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Reliability Test Item And Condition:

The reliability of products shall be satisfied with items listed below:

Confidence level: 90%.

LTPD: 10%.

| No. | Item | Test Conditions | Test Hours/ Cycles | Sample Sizes | Failure Judgment Criteria | Ac/ Re |
|-----|------------------------------------|---|--------------------------|-----------------|--------------------------------------|-----------|
| 1 | Reflow Soldering | TEMP.: 260 <u>+</u> 5 5secs | 6mins | 22pcs | | 0/1 |
| 2 | Temperature Cycle | H: +100 15mins 5 mins L: -40 15mins | 50Cycles | 22pcs | | 0/1 |
| 3 | Thermal Shock | H: +100 15mins 10secs L: -10 5mins | 50Cycles | 22pcs | Ic _(ON) L×0.8 L: Lower | 0/1 |
| 4 | High Temperature Storage | TEMP.: +100 | 1000hrs | 22pcs | Specification Limit | 0/1 |
| 5 | Lower Temperature Storage | TEMP.: -40 | 1000hrs | 22pcs | | 0/1 |
| 6 | DC Operating Life | V _{CE} =5V | 1000hrs | 22pcs | | 0/1 |
| 7 | High Temperature/ High Humidity | 85 / 85% R.H | 1000hrs | 22pcs | | 0/1 |



Please read the following notes before using the product:

1. Over-current-proof

Customer must apply resistors for protection, otherwise slight voltage shift will cause big current change (Burn out will happen).

2. Storage

2.1 Do not open moisture proof bag before the products are ready to use.

2.2 Before opening the package, the phototransistor should be kept at 30 or less and 90% RH or less.

2.3 The phototransistor should be used within a year.

2.4 After opening the package, the phototransistor should be kept at 30 or less and 70% RH or less.

2.5 The phototransistor should be used within 168 hours (7 days) after opening the package.

3. Soldering Iron

Each terminal is to go to the tip of soldering iron temperature less than 260 for 5 seconds within once in less than the soldering iron capacity 25W. Leave two seconds and more intervals, and do soldering of each terminal. Be careful because the damage of the product is often started at the time of the hand solder.

4. Repairing

Repair should not be done after the phototransistor had been soldered. When repairing is unavoidable, a double-head soldering iron should be used. It should be confirmed beforehand whether the characteristics of the phototransistor will or will not be damaged by repairing.

5. Caution in ESD

Static Electricity and surge damages the phototransistor. It is recommended to use a wrist band or anti-electrostatic glove when handling the phototransistor. All devices equipment and machinery must be properly grounded.